

IDS Form PTO/SB/08: Substitute for form 1449A/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>				<i>Application Number</i>	10/581,497
				<i>Filing Date</i>	June 2, 2006
				<i>First Named Inventor</i>	Babak HEIDARI et al.
				<i>Art Unit</i>	2822
				<i>Examiner Name</i>	Not yet assigned
<i>Sheet</i>	1	of	2	<i>Attorney Docket Number</i>	02386.0105

U.S. PATENTS AND PUBLISHED U.S. PATENT APPLICATIONS					
Examiner Initials	Cite No. ¹	Document Number	Issue or Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
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Note: Submission of copies of U.S. Patents and published U.S. Patent Applications is not required.

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Examiner Initials	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Translation ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				
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NONPATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Translation ⁶
		Heidari et al.; "LARGE SCALE NANOLITHOGRAPHY USING NANOIMPRINT LITHOGRAPHY"; Journal of Vacuum Science & Technology B, Vol. 17, No. 6, pages 2961-2964, (1999)	

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet

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of

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	Resnick et al.; "IMPRINT LITHOGRAPHY FOR INTEGRATED CIRCUIT FABRICATION"; Journal of Vacuum Science & Technology B, Vol. 21, No. 6, pages 2624-2631, (2003)	
	English language version of "Notification of the First Office Action" in corresponding Chinese App. No. 200510081756.4, Notification Date June 6, 2008.	
	English language version of "Notification of the Second Office Action" in corresponding Chinese App. No. 200510081756.4, Notification Date October 7, 2009.	
Examiner Signature		Date Considered

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